

MT8060N2

Features

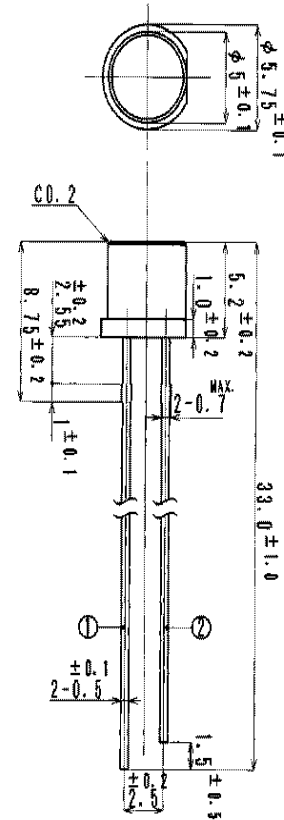
High Power Output
Wide Beam Angle

Applications

Optical Sensors
Bar Code Reader
Edge Sensing
Indicator

Maximum Ratings (Ta=25°C)

Characteristic	Symbol	Max.	Test Condition	Unit
Forward Current	I _F	50	–	mA
Pulsed Forward Current	I _{FP}	.50	tw=10μS, T=10mS	A
Reverse Voltage	V _R	5	–	V
Power Dissipation	P _D	120.00	–	mW
Operating Temperature	T _{opr}	–20 ~ +80	–	°C
Storage Temperature	T _{stg}	–30 ~+100	–	°C
Junction Temperature	T _j	100	–	°C
Soldering Temperature	T _{sol}	260	for 5 sec. max	°C



① Anode

② Cathode

Opto-Electrical Characteristics (Ta=25°C)

Characteristic	Symbol	Test Condition	Min	Typ	Max	Unit
Forward Voltage	V _F	I _F =20mA	–	1.80	2.20	V
Reverse Current	I _R	V _R =5V	–	–	100	μA
Power Output	PO	I _F =20mA	–	4.50	–	mW
Half Intensity Beam Angle	θ	–	–	± 40°	–	deg.
Peak Wavelength	λ _p	I _F =20mA	–	680	–	nm
Spectral Line Half Width	Δλ	I _F =20mA	–	25	–	nm
Rise Time	T _r	I _{FP} =20mA	–	30.00	–	ns
Fall Time	T _f	I _{FP} =20mA	–	30.00	–	ns
Temp Coefficient of PO	P/T	I _F =10mA	–	–.05	–	%/°C
Temp Coefficient of V _F	V/T	I _F =10mA	–	–1.50	–	mV/°C
Junction Capacitance	C _j	1 MHz, V=0V	–	20	–	pF

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MT8060N2 Graphs

